

DESCRIPTION

This series of surface mount diodes are specifically design for high volume surface mount applications. The GigaMite design is optimized for improved electrical and thermal performance over standard plastic package technology. Our patented dual orthogonal lead frame provides both exceptionally low thermal impedance and series inductance. Microsemi utilizes only the highest quality dielectric materials resulting in low loss tangent and physical stability even in harsh environments. The result is higher frequency coverage and greater stability than comparable plastic packages.

This series of devices meets RoHS requirements per EU Directive 2002/95/EC.

APPLICATIONS

Microsemi Lowell offers a variety of Varactor diodes in the GigaMite package style. Their low internal series inductance makes these products well suited for VCOs and VVFs through 5 GHz. Choose GMV1981 for low voltage battery applications. GMV15007 offers state of the art frequency linearity. GMV2114, GMV2134, and GMV2154 offer smooth wide ratio 20V tuning. GMV1542 offers high Q performance for lowest phase noise and loss.

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)

Rating	Symbol	Value	Unit
Maximum Leakage Current @80% of Rated V_B	I_R	100	nA
Storage Temperature	T_{STG}	-55 to +125	°C
Operating Temperature	T_{OP}	-55 to +125	°C

IMPORTANT: Specifications are subject to change.

For the most current data visit: www.MICROSEMI.com



These devices are ESD sensitive and must be handled using ESD precautions

KEY FEATURES

- Low Parasitics
 $L_P = 0.5$ nH Typical
 $C_P = 0.07$ pF Typical
- Surface Mount design
- Broadband Performance Through 5 GHz
- Available on Tape & Reel for Automated Pick & Place Assembly
- Small, SOD 323 Size Footprint
- RoHS Compliant ¹

APPLICATIONS/BENEFITS

- Frequency Linear VCO's
- Low Phase Noise VCO's
- Wide Bandwidth VCO's
- Voltage variable Filters
- Analog Phase Shifters
- VCXO's
- Performance through 5 GHz



¹ These devices are supplied with a matte tin finish suitable for RoHS compliant assembly.

Low Voltage / High Sensitivity Varactors

▶ **ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)**

Model Number	V _b (V) I _r =10μA (Min)	C _T (pF) ¹ @ V _r =1V (Min)	C _T (pF) ¹ @ V _r =2.5V (Min - Max)	C _T (pF) ¹ @ V _r =4V (Max)	C _T (pF) ¹ @ V _r =8V (Typ)	Q ² (Min)
GMV1981-GM1	12	1.2	0.7 - 1.1	0.5	0.25	1200

22V FLTVAR GigaMite

▶ **ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)**

Model Number	V _b (V) I _r =10μA (Min)	C _T (pF) ¹ @ V _r =0V (Min)	C _T (pF) ¹ @ V _r =4V (Min - Max)	C _T (pF) ¹ @ V _r =20V (Max)	Ratio C _{T0} /C _{T20} (Typ)	Q ² (Min)
GMV15007-GM1	22	2.5	0.9 - 1.3	0.5	8:1	1000

22V HyperAbrupt GigaMite

▶ **ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)**

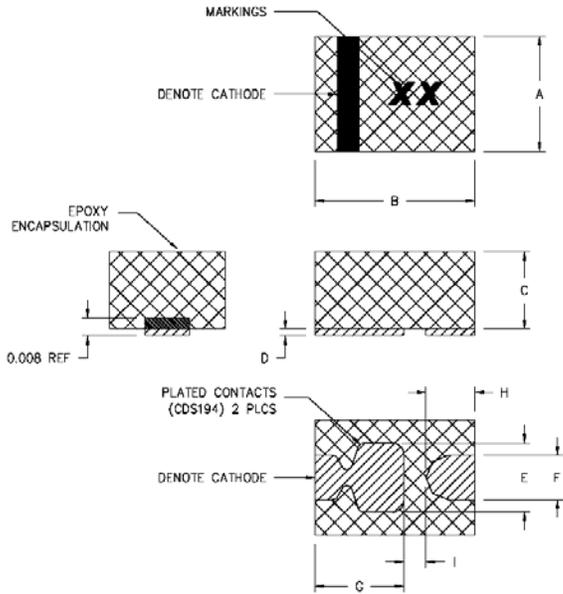
Model Number	V _b (V) I _r =10μA (Min)	C _T (pF) ¹ @ V _r =0V (Min)	C _T (pF) ¹ @ V _r =4V (Min-Max)	C _T (pF) ¹ @ V _r =20V (Max)	Ratio C _{T4} /C _{T20} (Typ)	Q ² (Min)
GMV2114-GM1	22	2.1	0.8 - 1.1	0.5	3.0	900
GMV2134-GM1	22	4.9	1.7 - 2.2	0.7	3.7	750
GMV2154-GM1	22	14	4.4 - 5.5	1.3	4.1	600

30V Abrupt Junction GigaMite

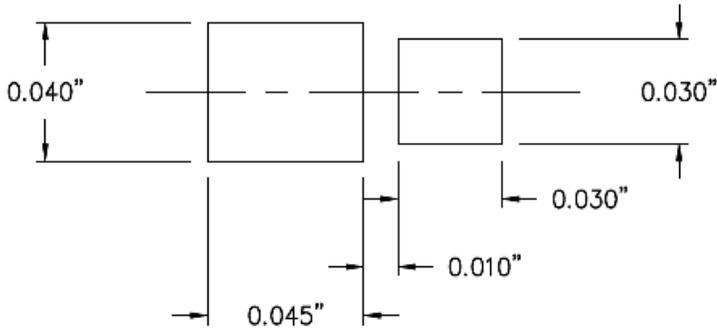
▶ **ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)**

Model Number	V _b (V) I _r =10μA (Min)	C _T (pF) ¹ @ V _r =0V (Min)	C _T (pF) ¹ @ V _r =4V (Min-Max)	C _T (pF) ¹ @ V _r =30V (Max)	Ratio C _{T0} /C _{T30} (Typ)	Q ² (Min)
GMV1542-GM1	30	2.4	1.0 - 1.3	0.75	3.4	3800

1. $f = 1\text{MHz}$.
2. $V=4\text{V}$, $f = 50\text{MHz}$

PACKAGE STYLE GM1


DIM	INCHES			MM		
	MIN	TYP	MAX	MIN	TYP	MAX
A	0.047	0.052	0.057	1.194	1.321	1.448
B	0.067	0.072	0.077	1.702	1.829	1.956
C	0.030	0.035	0.040	0.762	0.889	1.016
D	—	—	0.003	—	—	0.076
E	0.028	0.031	0.034	0.711	0.787	0.864
F	0.017	0.020	0.023	0.432	0.508	0.584
G	0.035	0.040	0.045	0.889	1.016	1.143
H	0.017	0.022	0.027	0.432	0.559	0.686
I	—	0.010	—	—	0.254	—

SUGGESTED SOLDER PAD LAYOUT


SUGGESTED SOLDER
PAD LAYOUT

